



**Absolute Maximum Ratings** (Notes 1 & 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage ( $V_{CC}$ )	-0.5 to +7.0V
DC Input Voltage ( $V_{IN}$ )	-1.5 to $V_{CC} + 1.5V$
DC Output Voltage ( $V_{OUT}$ )	-0.5 to $V_{CC} + 0.5V$
Clamp Diode Current ( $I_{IK}, I_{OK}$ )	$\pm 20$ mA
DC Output Current, per pin ( $I_{OUT}$ )	$\pm 35$ mA
DC $V_{CC}$ or GND Current, per pin ( $I_{CC}$ )	$\pm 70$ mA
Storage Temperature Range ( $T_{STG}$ )	-65°C to +150°C
Power Dissipation ( $P_D$ )	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. ( $T_L$ ) (Soldering 10 seconds)	260°C

**Operating Conditions**

	Min	Max	Units
Supply Voltage ( $V_{CC}$ )	2	6	V
DC Input or Output Voltage ( $V_{IN}, V_{OUT}$ )	0	$V_{CC}$	V
Operating Temp. Range ( $T_A$ )			
MM74HC	-40	+85	°C
MM54HC	-55	+125	°C
Input Rise or Fall Times ( $t_r, t_f$ )			
$V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns

**DC Electrical Characteristics**

Symbol	Parameter	Conditions	$V_{CC}$	$T_A = 25^\circ C$			74HC	54HC	Units
						$T_A = -40$ to $85^\circ C$	$T_A = -55$ to $125^\circ C$		
				Typ	Guaranteed Limits				
$V_{IH}$	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V	
			4.5V		3.15	3.15	3.15	V	
			6.0V		4.2	4.2	4.2	V	
$V_{IL}$	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V	
			4.5V		1.35	1.35	1.35	V	
			6.0V		1.8	1.8	1.8	V	
$V_{OH}$	Minimum High Level Output Voltage	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 20 \mu A$	2.0V	2.0	1.9	1.9	1.9	V	
			4.5V	4.5	4.4	4.4	4.4	V	
			6.0V	6.0	5.9	5.9	5.9	V	
		$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 6.0$ mA $ I_{OUT}  \leq 7.8$ mA	4.5V	4.2	3.98	3.84	3.7	V	
			6.0V	5.7	5.48	5.34	5.2	V	
$V_{OL}$	Maximum Low Level Output Voltage	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 20 \mu A$	2.0V	0	0.1	0.1	0.1	V	
			4.5V	0	0.1	0.1	0.1	V	
			6.0V	0	0.1	0.1	0.1	V	
		$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 6.0$ mA $ I_{OUT}  \leq 7.8$ mA	4.5V	0.2	0.26	0.33	0.4	V	
			6.0V	0.2	0.26	0.33	0.4	V	
$I_{IN}$	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V		$\pm 0.1$	$\pm 1.0$	$\pm 1.0$	$\mu A$	
$I_{OZ}$	Maximum TRI-STATE Output Leakage Current	$V_{IN} = V_{IH}$ or $V_{IL}$ , $OC = V_{IH}$ $V_{OUT} = V_{CC}$ or GND	6.0V		$\pm 0.5$	$\pm 5$	$\pm 10$	$\mu A$	
$I_{CC}$	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \mu A$	6.0V		8.0	80	160	$\mu A$	

**Note 1:** Absolute Maximum Ratings are those values beyond which damage to the device may occur.

**Note 2:** Unless otherwise specified all voltages are referenced to ground.

**Note 3:** Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C; ceramic "J" package: -12 mW/°C from 100°C to 125°C.

**Note 4:** For a power supply of 5V  $\pm 10\%$  the worst case output voltages ( $V_{OH}$  and  $V_{OL}$ ) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case  $V_{IH}$  and  $V_{IL}$  occur at  $V_{CC} = 5.5V$  and 4.5V respectively. (The  $V_{IH}$  value at 5.5V is 3.85V.) The worst case leakage current ( $I_{IN}$ ,  $I_{CC}$ , and  $I_{OZ}$ ) occur for CMOS at the higher voltage and so the 6.0V values should be used.

\*\* $V_{IL}$  limits are currently tested at 20% of  $V_{CC}$ . The above  $V_{IL}$  specification (30% of  $V_{CC}$ ) will be implemented no later than Q1, CY89.

**AC Electrical Characteristics**  $V_{CC} = 5V$ ,  $T_A = 25^\circ C$ ,  $t_r = t_f = 6$  ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
$t_{PHL}$ , $t_{PLH}$	Maximum Propagation Delay, Data to $\bar{Q}$	$C_L = 45$ pF	18	25	ns
$t_{PHL}$ , $t_{PLH}$	Maximum Propagation Delay, Enable to $\bar{Q}$	$C_L = 45$ pF	21	30	ns
$t_{PZH}$ , $t_{PZL}$	Maximum Output Enable Time	$R_L = 1$ k $\Omega$ $C_L = 45$ pF	20	28	ns
$t_{PHZ}$ , $t_{PLZ}$	Maximum Output Disable Time	$R_L = 1$ k $\Omega$ $C_L = 5$ pF	18	25	ns
$t_S$	Minimum Set Up Time			5	ns
$t_H$	Minimum Hold Time			10	ns
$t_W$	Minimum Pulse Width			16	ns

**AC Electrical Characteristics**  $V_{CC} = 2.0V - 6.0V$ ,  $C_L = 50$  pF,  $t_r = t_f = 6$  ns (unless otherwise specified)

Symbol	Parameter	Conditions	$V_{CC}$	$T_A = 25^\circ C$		74HC $T_A = -40$ to $85^\circ C$		54HC $T_A = -55$ to $125^\circ C$		Units
				Typ		Guaranteed Limits				
$t_{PHL}$ , $t_{PLH}$	Maximum Propagation Delay, Data to $\bar{Q}$	$C_L = 50$ pF	2.0V	50	150	188		225		ns
			2.0V	80	200	250		300		ns
		$C_L = 150$ pF	4.5V	22	30	37		45		ns
			4.5V	30	40	50		60		ns
$t_{PHL}$ , $t_{PLH}$	Maximum Propagation Delay, Enable to $\bar{Q}$	$C_L = 50$ pF	6.0V	19	26	31		39		ns
			6.0V	26	35	44		53		ns
		$C_L = 150$ pF	2.0V	63	175	220		263		ns
			2.0V	110	225	280		338		ns
$t_{PZH}$ , $t_{PZL}$	Maximum Output Enable Time	$R_L = 1$ k $\Omega$	4.5V	25	35	44		52		ns
			4.5V	35	45	56		68		ns
		$C_L = 50$ pF	6.0V	21	30	37		45		ns
			6.0V	28	39	49		59		ns
$t_{PHZ}$ , $t_{PLZ}$	Maximum Output Disable Time	$R_L = 1$ k $\Omega$	2.0V	50	150	188		225		ns
			4.5V	21	30	37		45		ns
		$C_L = 50$ pF	6.0V	19	26	31		39		ns
			6.0V	26	35	44		53		ns
$t_S$	Minimum Set Up Time		2.0V		50	60		75		ns
			4.5V		9	13		15		ns
			6.0V		9	11		13		ns
			2.0V		5	5		5		ns
$t_H$	Minimum Hold Time		4.5V		5	5		5		ns
			6.0V		5	5		5		ns
			2.0V	30	80	100		120		ns
			4.5V	10	16	20		24		ns
$t_W$	Minimum Pulse Width		6.0V	9	14	18		20		ns
			2.0V	25	60	75		90		ns
			4.5V	7	12	15		18		ns
			6.0V	6	10	13		15		ns
$t_{THL}$ , $t_{TLH}$	Maximum Output Rise and Fall Time, Clock	$C_L = 50$ pF	2.0V	25	60	75		90		ns
			4.5V	7	12	15		18		ns
			6.0V	6	10	13		15		ns
$C_{PD}$	Power Dissipation Capacitance (Note 5)	(per latch) $OC = V_{CC}$ $OC = Gnd$		30					pF	
				50					pF	
$C_{IN}$	Maximum Input Capacitance			5	10	10		10		pF
$C_{OUT}$	Maximum Output Capacitance			15	20	20		20		pF

Note 5:  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} V_{CC} f + I_{CC}$ .